

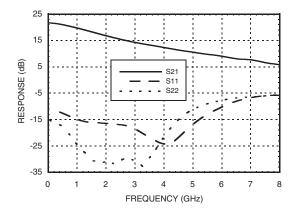
# HMC481MP86 / 481MP86E

v03.0810

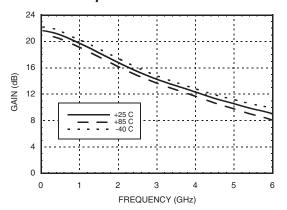


# SiGe HBT GAIN BLOCK MMIC AMPLIFIER, DC - 5 GHz

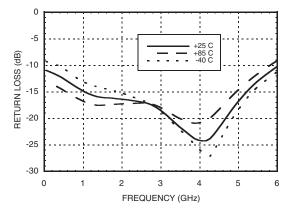
#### **Broadband Gain & Return Loss**



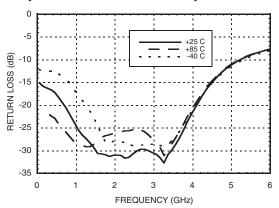
#### Gain vs. Temperature



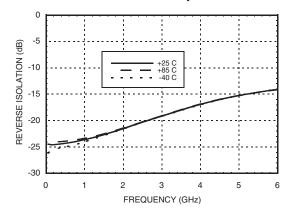
## Input Return Loss vs. Temperature



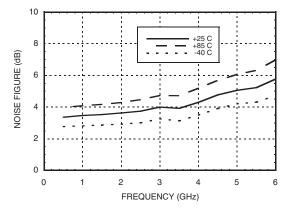
### **Output Return Loss vs. Temperature**



#### Reverse Isolation vs. Temperature



## Noise Figure vs. Temperature



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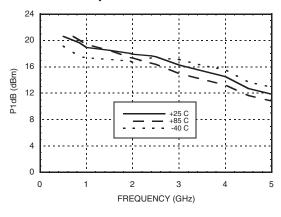


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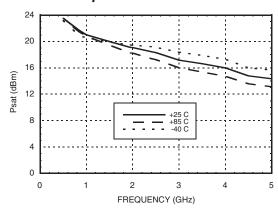


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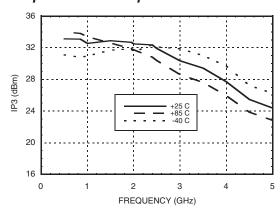
#### P1dB vs. Temperature



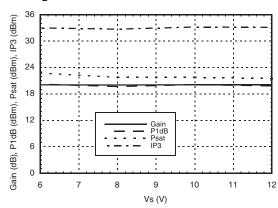
#### Psat vs. Temperature



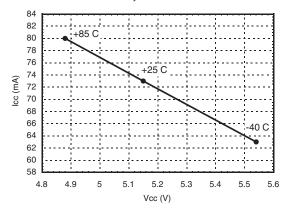
## Output IP3 vs. Temperature



## Gain, Power & Output IP3 vs. Supply Voltage for Constant Id= 74 mA @ 850 MHz



# Vcc vs. Icc Over Temperature for Fixed Vs= 8V, RBIAS= 39 Ohms



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# HMC481MP86 / 481MP86E

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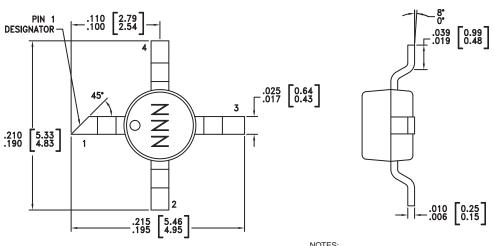
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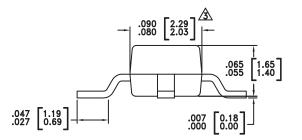
## **Absolute Maximum Ratings**

| Collector Bias Voltage (Vcc)                                    | +6 Vdc         |
|---|----------------|
| Collector Bias Current (Icc)                                    | 100 mA         |
| RF Input Power (RFIN)(Vcc = +5.15 Vdc)                          | +10 dBm        |
| Junction Temperature  | 150 °C         |
| Continuous Pdiss (T = 85 °C)<br>(derate 11.6 mW/°C above 85 °C) | 0.753 W        |
| Thermal Resistance (junction to lead)                           | 86.3 °C/W      |
| Storage Temperature   | -65 to +150 °C |
| Operating Temperature   | -40 to +85 °C  |
| ESD Sensitivity (HBM)   | Class 1A       |



## **Outline Drawing**





#### NOTES:

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- DIMENSIONS ARE IN INCHES [MILLIMETERS]
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- 4. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.
- 5. THE MICRO-P PACKAGE IS DIMENSIONALLY COMPATIBLE WITH THE "MICRO-X PACKAGE"

### Package Information

| Part Number | Package Body Material                              | Lead Finish   | MSL Rating | Package Marking |
|-------------|--|---------------|------------|-----------------|
| HMC481MP86  | Low Stress Injection Molded Plastic                | Sn/Pb Solder  | MSL1 [1]   | 481             |
| HMC481MP86E | RoHS-compliant Low Stress Injection Molded Plastic | 100% matte Sn | MSL1 [2]   | <u>481</u>      |

<sup>[1]</sup> Max peak reflow temperature of 235 °C

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<sup>[2]</sup> Max peak reflow temperature of 260  $^{\circ}\text{C}$ 



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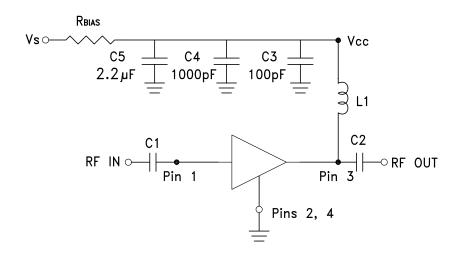


# SiGe HBT GAIN BLOCK MMIC AMPLIFIER, DC - 5 GHz

## **Pin Descriptions**

| Pin Number | Function | Description  | Interface Schematic |
|------------|----------|--|---------------------|
| 1          | RFIN     | This pin is DC coupled. An off chip DC blocking capacitor is required. | RFOUT               |
| 3          | RFOUT    | RF output and DC Bias (Vcc) for the output stage.                      |                     |
| 2, 4       | GND      | These pins must be connected to RF/DC ground.                          | GND<br>=            |

## **Application Circuit**



# Recommended Bias Resistor Values for Icc= 74 mA, Rbias= (Vs - Vcc) / Icc

| Supply Voltage (Vs) | 6V    | 8V    | 10V   | 12V  |
|---------------------|-------|-------|-------|------|
| RBIAS VALUE         | 11 Ω  | 39 Ω  | 62 Ω  | 91 Ω |
| RBIAS POWER RATING  | 1/8 W | 1/4 W | 1/2 W | 1 W  |

#### Note:

- 1. External blocking capacitors are required on RFIN and RFOUT.
- 2. RBIAS provides DC bias stability over temperature.

## Recommended Component Values for Key Application Frequencies

| Component | Frequency (MHz) |        |        |        |        |        |        |
|-----------|-----------------|--------|--------|--------|--------|--------|--------|
| Component | 50              | 900    | 1900   | 2200   | 2400   | 3500   | 5000   |
| L1        | 270 nH          | 56 nH  | 18 nH  | 18 nH  | 15 nH  | 8.2 nH | 6.8 nH |
| C1, C2    | 0.01 μF         | 100 pF |

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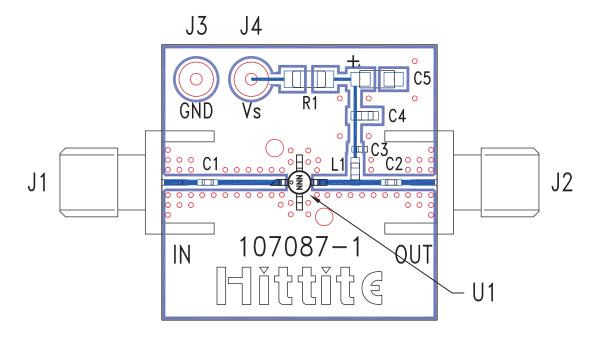
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# SiGe HBT GAIN BLOCK MMIC AMPLIFIER, DC - 5 GHz

#### **Evaluation PCB**



#### List of Materials for Evaluation PCB 107490 [1]

| Item    | Description                  |
|---------|------------------------------|
| J1 - J2 | PCB Mount SMA Connector      |
| J3 - J4 | DC Pin                       |
| C1, C2  | Capacitor, 0402 Pkg.         |
| C3      | 100 pF Capacitor, 0402 Pkg.  |
| C4      | 1000 pF Capacitor, 0603 Pkg. |
| C5      | 2.2 µF Capacitor, Tantalum   |
| R1      | Resistor, 1210 Pkg.          |
| L1      | Inductor, 0603 Pkg.          |
| U1      | HMC481MP86 / HMC481MP86E     |
| PCB [2] | 107087 Evaluation PCB        |

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.